TOSHIBA Fast Recovery Diode Silicon Diffused Type

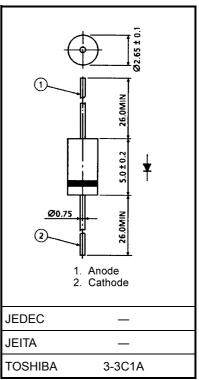
TVR1B,TVR1G,TVR1J

TV Applications (fast recovery)

- Average Forward Current: $I_{F(AV)} = 0.5 \text{ A} (Ta = 65^{\circ}\text{C})$
- Repetitive Peak Reverse Voltage: V_{RRM} = 100, 400, 600 V
- Reverse Recovery Time: trr = 2.0 µs

Maximum Ratings (Ta = 25°C)

| Characteristics | | Symbol | Rating | Unit | |
|---|-------|---------------------|------------|------|--|
| Repetitive peak reverse voltage | TVR1B | | 100 | V | |
| | TVR1G | V _{RRM} | 400 | | |
| | TVR1J | | 600 | | |
| Average forward current (Ta = 65°C) | | I _{F (AV)} | 0.5 | А | |
| Peak one cycle surge forward current (non repetitive) | | I _{FSM} | 10 (50 Hz) | А | |
| Junction temperature | | Tj | -40~125 | °C | |
| Storage temperature range | | T _{stg} | -40~125 | °C | |

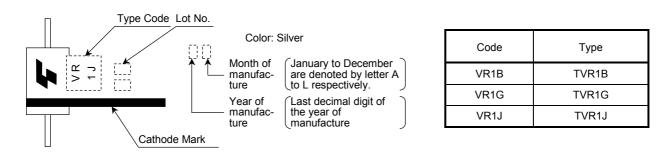


Weight: 0.3 g (typ.)

Electrical Characteristics (Ta = 25°C)

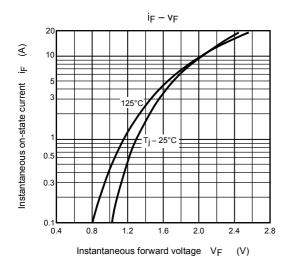
| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---------------------------------|---------------------|--|-----|------|-----|------|
| Peak forward voltage | V _{FM} | I _{FM} = 0.5 A | | _ | 1.2 | V |
| Repetitive peak reverse current | I _{RRM} | V _{RRM} = Rated | _ | _ | 10 | μA |
| Reverse recovery time | t _{rr} (1) | $I_{F} = 20 \text{ mA}, I_{R} = 1 \text{ mA}$ | _ | _ | 2.0 | μs |
| | t _{rr} (2) | I _F = 100 mA, I _R = 100 mA | _ | 0.3 | _ | |

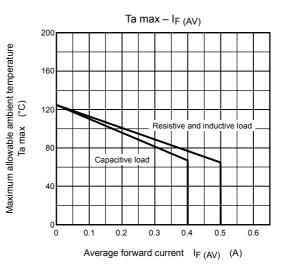
Marking

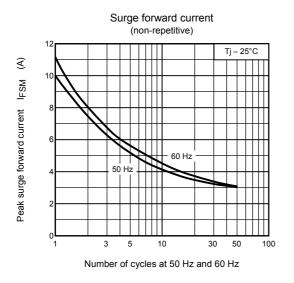


Unit: mm

TOSHIBA







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Handbook" etc.,

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